

Peak Emission Wavelength: 855nm

The 850nm Point Source Series is designed for applications requiring high accuracy and precision as well as uniform spectral emission. Custom package solutions and sorting are available.

FEATURES

- > 3.5×2.2×1.24 Flat Top Ceramic SMT
- > Emitting Window Diameter Φ 150 μ m
- > High Reliability / High Output Power

APPLICATIONS

- > Optical Scanning
- > Linear & Rotary Encoder
- > Edge Sensing
- > Optical Sensors



Absolute Maximum Ratings (Ta=25°C)

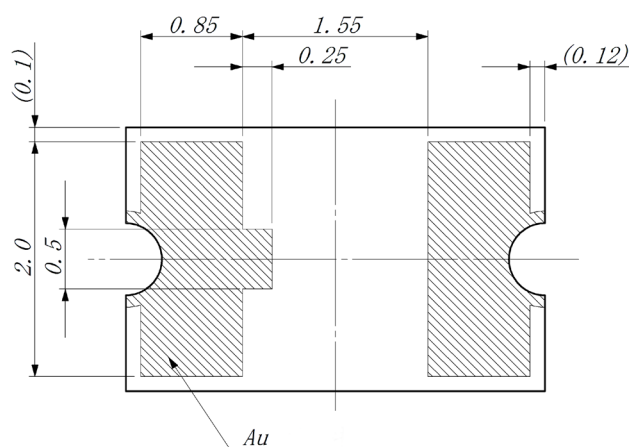
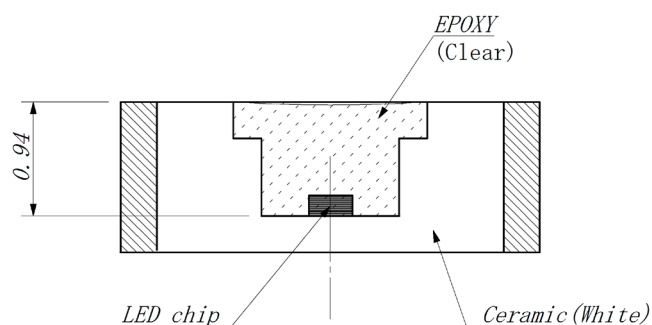
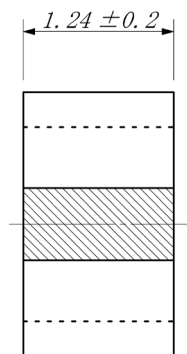
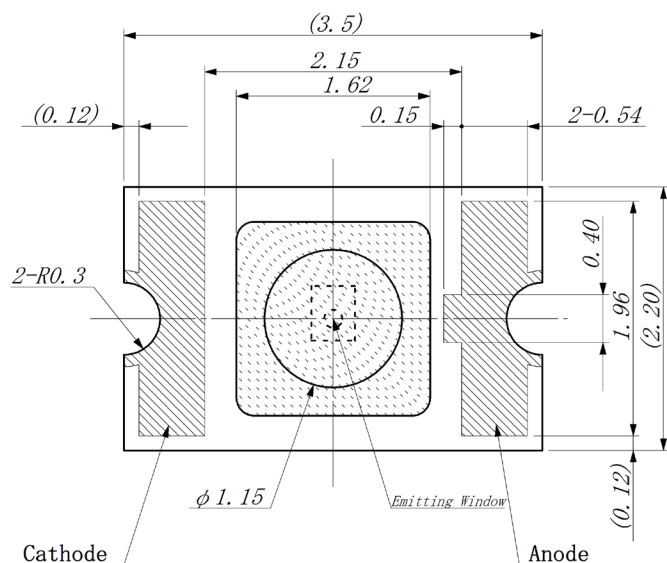


ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	60	mA
Forward Current (Pulse)*1	IFP	0.4	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	110	mW
Operating Temperature Range	Topr	-20 ~ +85	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C

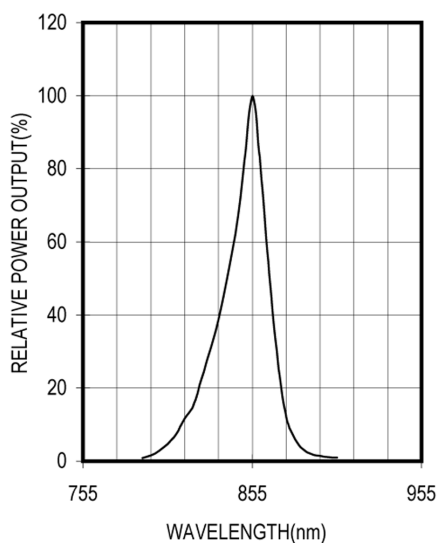
*1: Tw=10 μ sec, T=10msec.

Electrical & Optical Characteristics (Ta = 25°C)

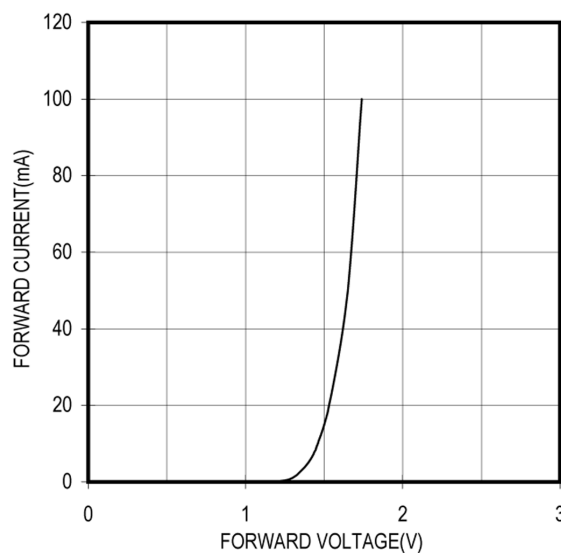
ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=20mA	--	4.5	--	mW
Forward Voltage	VF	IF=20mA	--	1.7	2.2	V
Reverse Current	IR	VR=5V	--	--	100	μ A
Peak Emission Wavelength	λ_p	IF=20mA	--	855	--	nm
Spectral Line Half Width	$\Delta\lambda$	IF=20mA	--	40	--	nm
Half Intensity Beam Angle	Θ	IF=20mA	--	± 50	--	deg

Unit: mm, Tolerance: ± 0.2

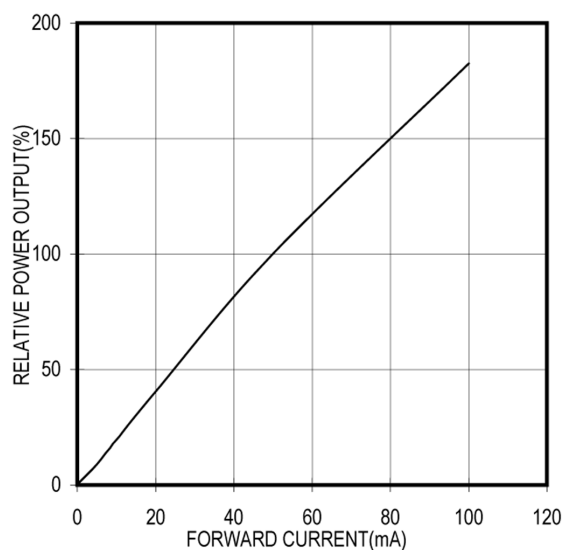
SPECTRAL OUTPUT



FORWARD I-V CHARACTERISTICS



RELATIVE POWER vs FORWARD CURRENT



RADIATION PATTERN

